

Supplementary Data

A Portable and Reusable Sensor System Based on Graphene for Real-Time and Sensitive Detection of Lead Ions in Water

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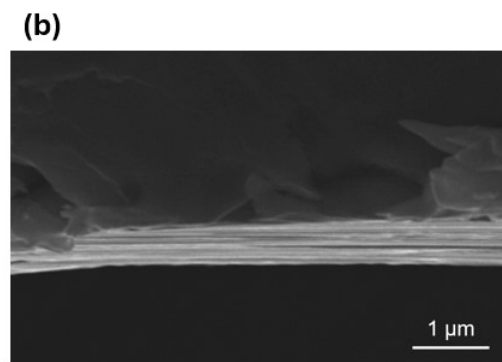
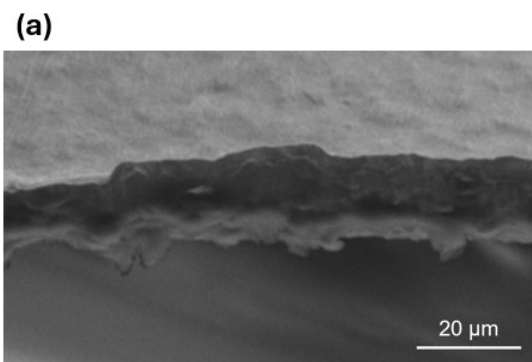


Figure S1. Cross-section SEM images of the full coverage films from (a) pristine graphene ink and (b) 3x diluted graphene ink.

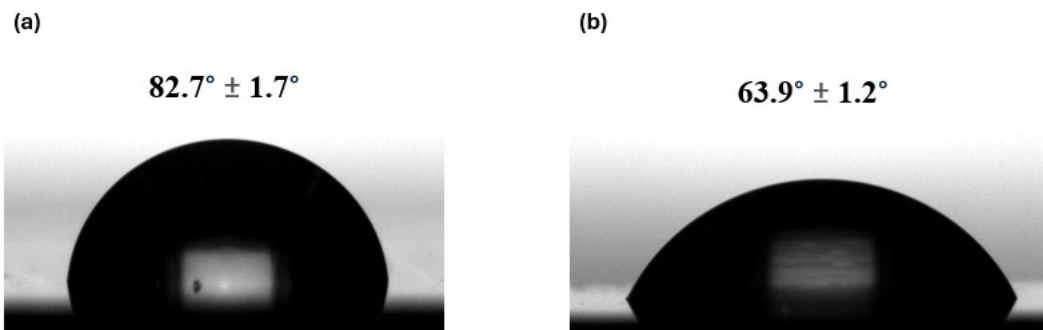


Figure S2. Contact angle measurements and analysis of (a) pristine graphene thin film and (b) PBA-functionalized graphene thin film.

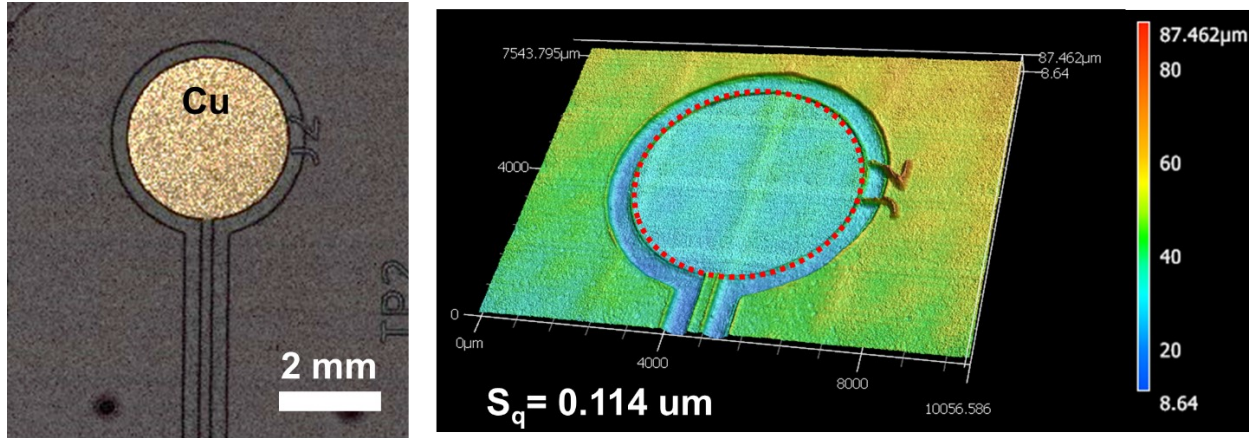


Figure S3. Confocal micrographs of a bare Cu pad on a sensor PCB showing the surface roughness (S_q) of 0.114 μm . The surface roughness (S_q) of Si wafer is 0.022 μm for comparison.

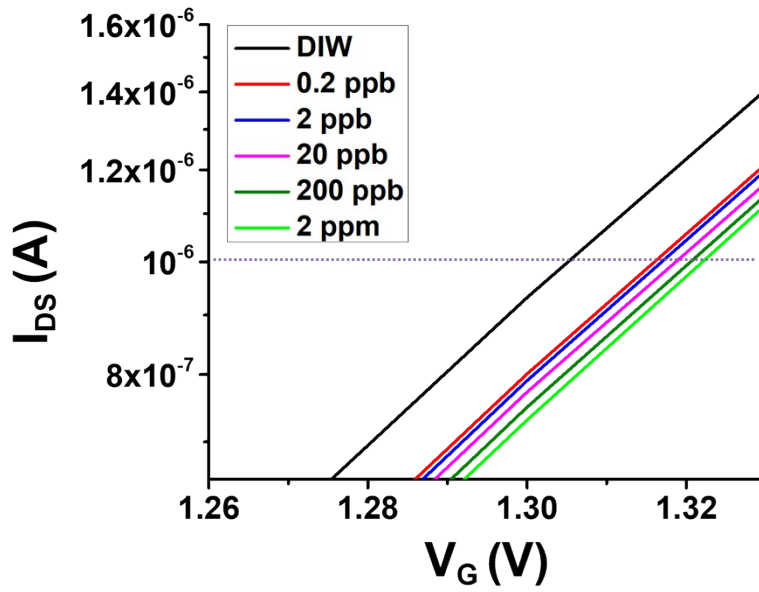


Figure S4. Transfer curves of the MOSFET upon detection of lead ions ranging from 0.2 ppb to 2 ppm using thick G-film sensor.

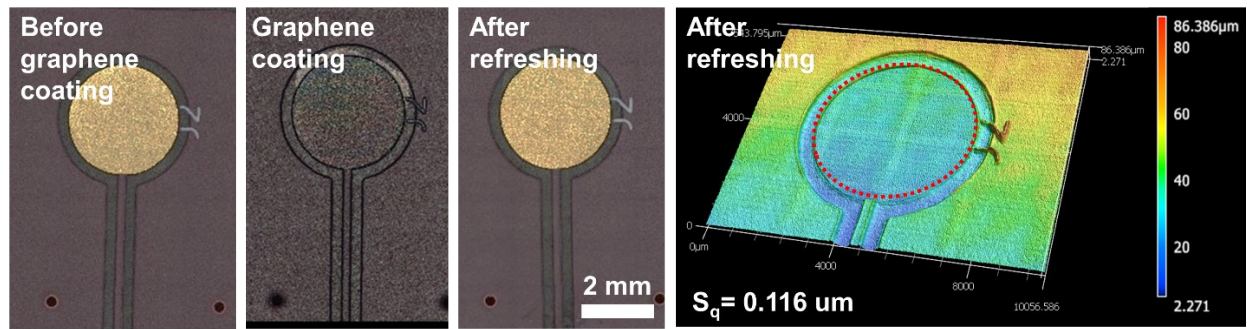


Figure S5. Confocal micrographs of a Cu pad from a sensor PCB before and after the refreshing process. The surface roughness (S_q) of the Cu pad after refreshing is 0.116 μm , comparable to that of the original Cu pad.

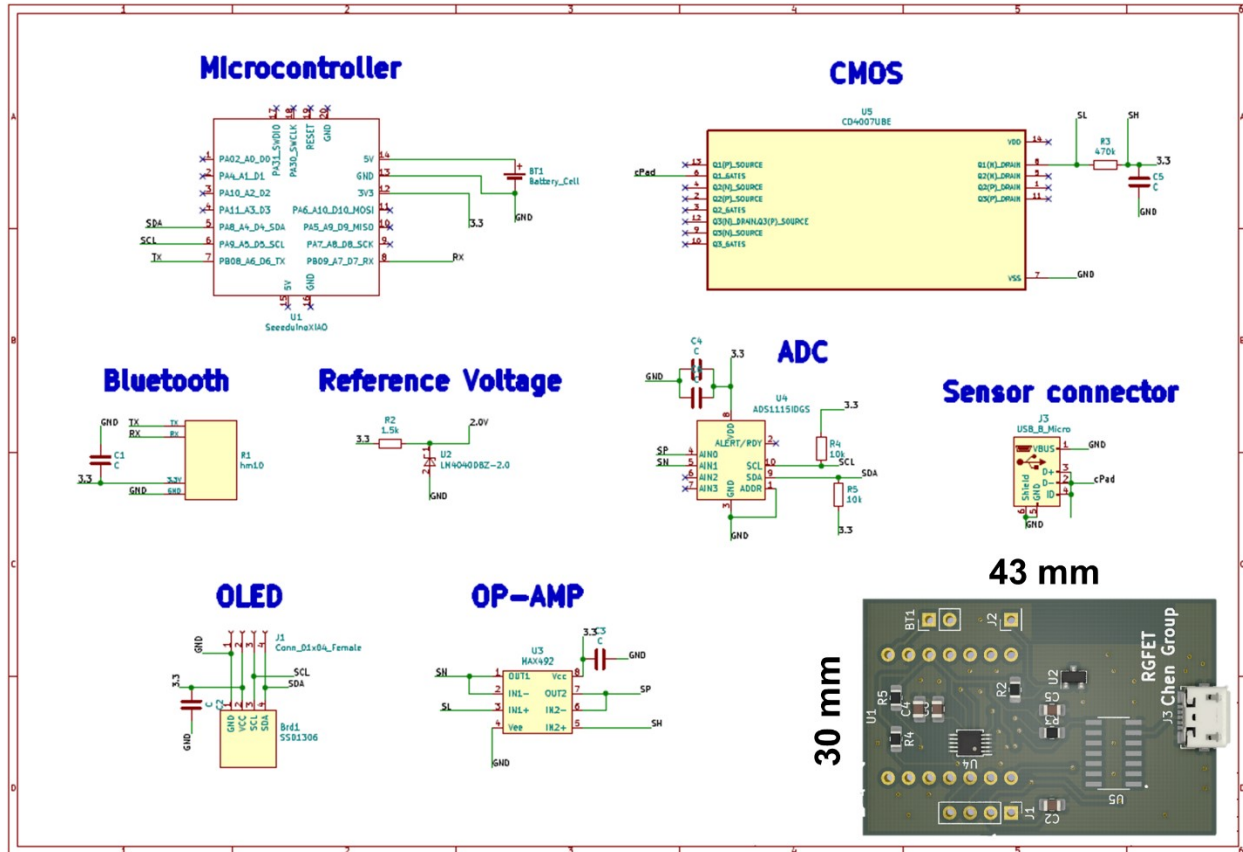


Figure S6. A circuit diagram of the portable sensor analyzer.

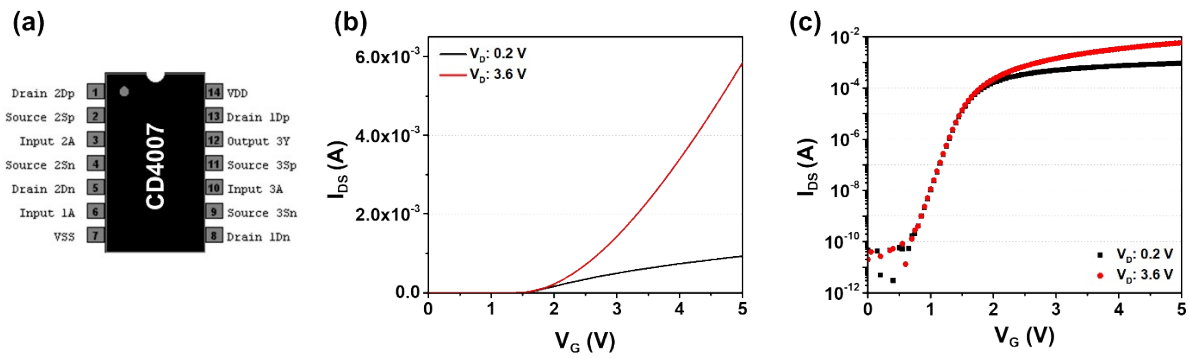


Figure S7. Characterization of a commercial n-type MOSFET. (a) A MOSFET (CD4007) used to construct the portable sensor system. (b) Transfer characteristic curves of the MOSFET as a function of gate and drain voltages. (c) Semi-logarithmic curves of those shown in (b).

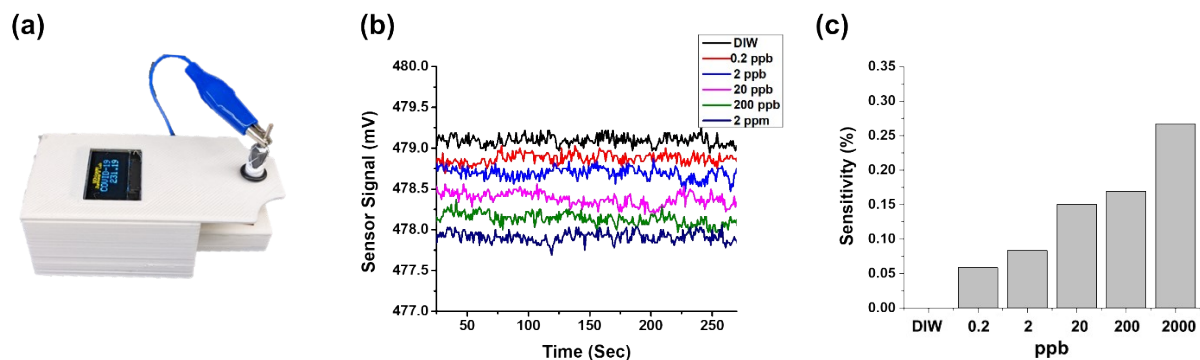


Figure S8. Lead ion detection using the portable sensor system. (a) The portable sensor with a sensor PCB bearing a thick G-film. (b) A real-time detection with respect to lead ion concentrations. (c) Sensitivity of the portable sensor toward lead ions using the thick G-film.